

Spring 2022 EE214 Experiment 4

Bipolar Junction Transistor Characteristics

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1 Introduction

In this experiment, using diode test method checking if BJT transistor is NPN or PNP will be applied ,and setting up a correct test environment with BenchVue will be learned Afterwards, input-output characteristics of both NPN and PNP bipolar junction transistors will be investigated.

2 Experimental Results and Discussion

The results of the experiment are discussed in the following steps.

2.1 Step 1

2.2 Step 2

In this part of the experiment, I_B vs V_{BE} characteristics of the NPN type BJT transistor is obtained. After setting up the following common emitter circuit in the Figure X, a test environment named BenchVue Test Flow is designed by following the steps below:

- i. Initialize and launch the devices. Launch the program BenchVue, which you can find on the desktop. In this experiment, we will use the digital multimeter and DC power supply. Firstly, turn on these devices manually. Then, launch the devices “DMM” (Digital Multimeter) and “Power Supply” by double clicking on their icons, which you can find at the lower right corner of the BenchVue screen. This action will activate the remote mode on these devices. In remote mode, control of these devices are completely transferred to the BenchVue program and you can no longer control the devices using their buttons. Observe that the launched devices are now at the lower left corner of the screen. You can reach the control panel of the devices by double clicking on them. Take a look at the control panel of both devices.
- ii. Construct the test flow. Test flow is a sequence of commands through which we can control the settings of devices and take measurements from the devices. Open the control panel of the Power supply. You will see three channels, each of which having a separate panel. +6V, +25V, and -25V outputs of the DC power supply are referred as the first, second and the third channels, respectively. Output state of these channels are at the upper right corner of the panel belonging to each channel, on which either “On” or “Off” is written. As a first step, we need to switch on the output states of the channels that we will use. In this experiment, we will use +6V (CH1) and +25V (CH2) outputs of the DC power supply. Click on the orange box enclosing the output states of these channels and drag them, respectively, into the test flow on the right hand side of the screen. Choose “Set”, and choose “On”. Click and drag the orange box enclosing “Voltage Setting” of +25V output (CH2) into the test flow. Choose “Set”. Enter 9V into the box. Click and drag the orange box enclosing “Voltage Setting” of +6V output (CH1) into the test flow. Choose “Sweep”. Enter the values in order for this source to sweep from 100 mV to 2V by 200mV increments. Next, we will fill in the actions that are needed in each increment inside this sweep box. For each value of this source, we will take measurements. Always, we need to put some delay before taking measurements. Inside the sweep box, place a “Delay” block of 1 second. You can find it in “More Blocks” \hookrightarrow “Basic Blocks”. We will obtain the base current from the reading of the multimeter. Since we want to use that in a plot, we should assign that reading to a variable. Create a variable named “Ib” from “More Blocks” \hookrightarrow “Variables” \hookrightarrow “Create Variable”. In “More Blocks” \hookrightarrow “Variables”, drag the label “Set” into the test flow. Then, drag the purple label for “Ib” to the left of “=” sign. Open the control panel of the digital multimeter (DMM). Set the “Measurement” as “DC Current”. Now the DMM works as an ammeter and please be sure that you have connected it into your circuit in series. You can see the readout panel at the right side of the control panel of DMM. Click and drag the readout box into the right of the “=”

sign, so that the current reading is assigned to the variable “Ib”. We will calculate the base-emitter voltage and assign it into a variable named “Vbe”. Create this variable and prepare the assignment procedure just as you did for “Ib” in previous step. (Repeat the procedure) “Vbe” is equal to voltage drop across the base resistor subtracted from the voltage value of 6V power supply. Using subtraction and multiplication boxes fill in the boxes on right. Assignment of “Vbe” was the last step that will be done inside the sweep. Set the output states as “Off” outside the sweep box which will conclude the flow. At the end, the test flow should look like Figure x.

- iii. By using multimeter as an ammeter(HP34401A), clicked on run button. Then, by selecting X-Y chart $I_B vs V_{BE}$ plot is obtained as in the Figure x.

Afterwards, designed circuit is tested on this environment and as seen in the Figure X, plot is like i-v characteristics of a diode with opening voltage is around 600mV, since Vbe is a PN junction. If it is commented on it, it can be said that after V_{BE} is passed 600mV current starts to flow, so V_{BE} can be called opening voltage.

2.3 Step 3

2.3.1 a)

In this part, circuit in Figure x is set and I_C vs V_{CB} characteristics of NPN transistor is investigated by again setting up an proper test environment using BenchVue. Since there are 2 voltage sources to be swept, first +25V channel is swept from 4V to 6V with steps of 1V, and then other source(6V channel) is swept inside of previous swept block from 1V to 6V with 0.5V steps. Afterwards, following plot is obtained in Figure x. The reason why we observed I_C current while V_{CB} is negative is because V_{BC} is positive and allows current to flow from base to collector.

2.3.2 b)

For this step, circuit in Figure X is set in order to observe I_C vs V_{BC} characteristics of PNP transistor(C557B) with a suitable test environment as in previous part in BenchVue. To be able to run the circuit in forward bias B-E junction and use same the environment settings with previous part in this part, voltage sources should be reverse connected for the Figure x. Then, step 3 part a) is repeated for this circuit and Figure x is obtained. Because of the diode model, the fact that the direction definition of I_C is changed is noted that.

2.4 Step 4

3 Conclusion

In this experiment, using diode test method checking if BJT transistor is NPN or PNP will be applied, and setting up a correct test environment with BenchVue is learned. Afterwards, input-output characteristics of both NPN and PNP bipolar junction transistors are investigated.

Appendix A

- PreLab Preparation 3 hours
- Experimental Work 2 hours
- Report Writing 8 hours

Appendix B

In this experiment, since the values the students obtained in the lab is quite close to the data provided by the lab assistants, it is preferred to use the data obtained by the students.